

backward-compatible with Bluetooth 3.0, 2.0 or 1.2 systems.

It incorporates Bluetooth 1M/2M/3Mbps RF, single-cycle 8bit MCU, TX/RX modem, 5-port memory controller, task/hopping controller, UART interface, and MICROCHIP's own Bluetooth software stack to achieve the required BT v4.1 with EDR functions.

To provide the superior audio and voice quality, it also integrates a DSP co-processor, a PLL, and a CODEC dedicated for voice and audio applications.

For voice, not only basic CVSD encoding and decoding but also enhanced noise reduction and echo cancellation are implemented by the built-in DSP to achieve better quality in both sending and receiving sides. For the enhanced

audio applications, SBC/AAC_LC decoding functions can be also carried out by DSP to satisfy Bluetooth A2DP requirements.

In addition, to minimize the external components required for portable devices, a battery voltage sensor, battery charger, a switching regulator and LDO are integrated to reduce system BOM cost for various Bluetooth applications.

As the market of portable/wireless speakers demand is increasing, a 1 channels 2.3W class-D amplifier which provides up to 100dB SNR is also built-in to reduce BOM cost and PCB area.

Applications

- Mono headsets with A2DP
- Mono speakerphones

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Abbreviations List:

HFP: Hands-free Profile
AVRCP: Audio Video Remote Control Profile
A2DP: Advanced Audio Distribution Profile
PBAP: Phone Book Access Profile
HSP: Headset Profile
SPP: Serial Port Profile
NFC: Near Field Communication
CDA: Class D Amplifier
SCMS-T: Serial Copy Management System

1.0 DEVICE OVERVIEW

The mono audio chip series include IS2008S, IS2010S, IS2013S and IS2015S chip. The chip integrates Bluetooth 4.1 radio transceiver, PMU, DSP and 1-channel CDA (Class D Amplifier). Figure 1-1 shows the application block diagram.

FIGURE 1-1: APPLICATION BLOCK DIAGRAM

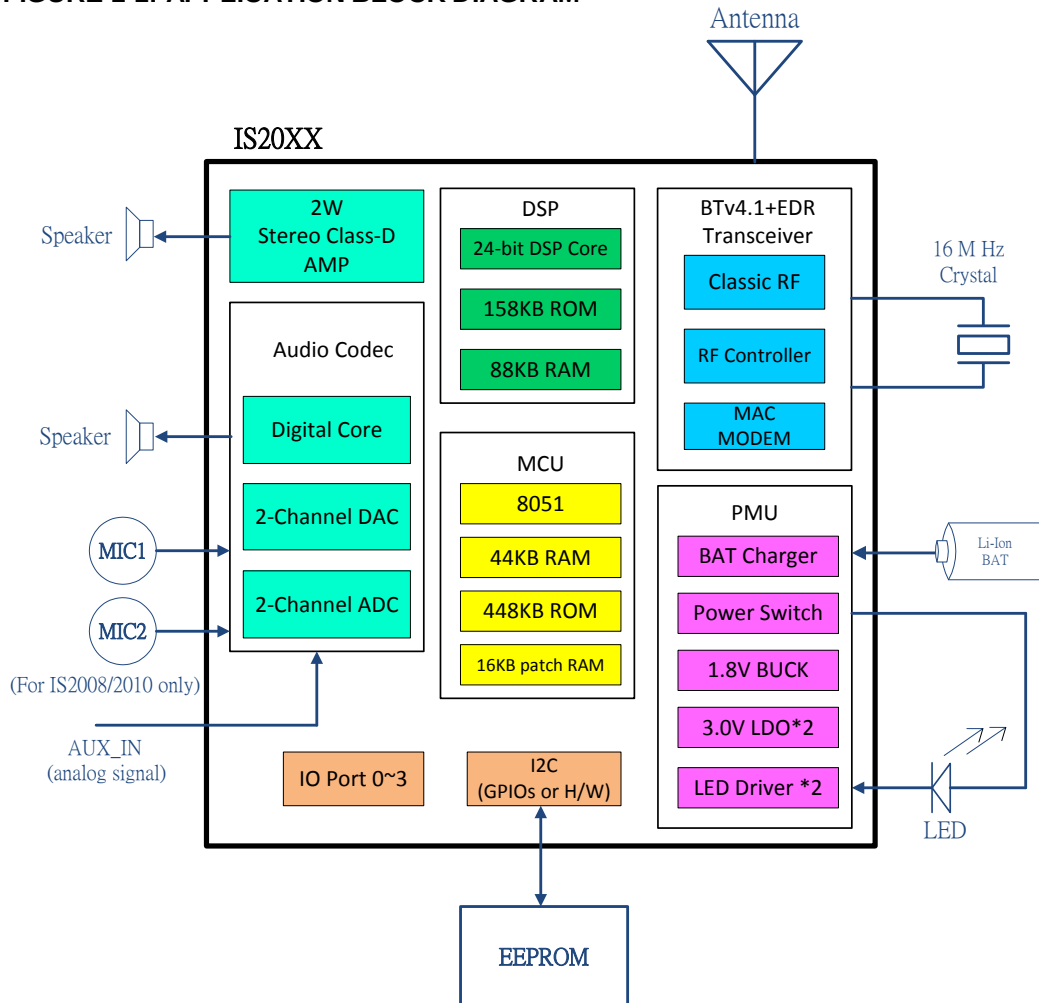
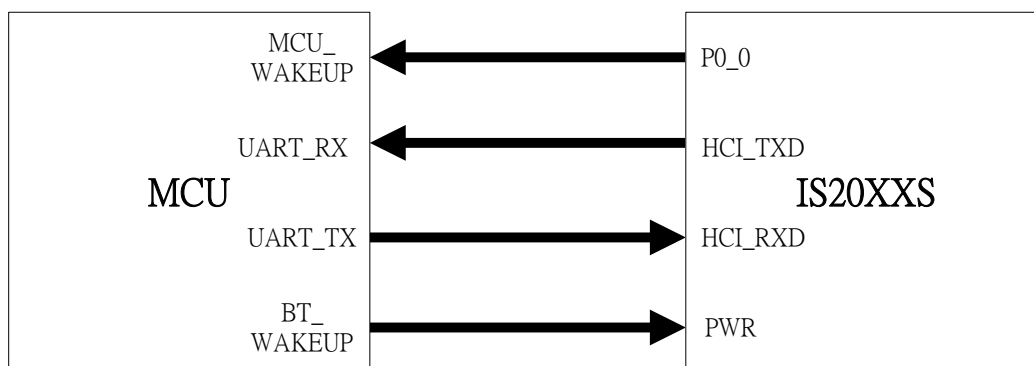


FIGURE 1-2: INTERFACE BETWEEN MCU AND IS20XX CHIP



2.0 KEY FEATURES TABLE

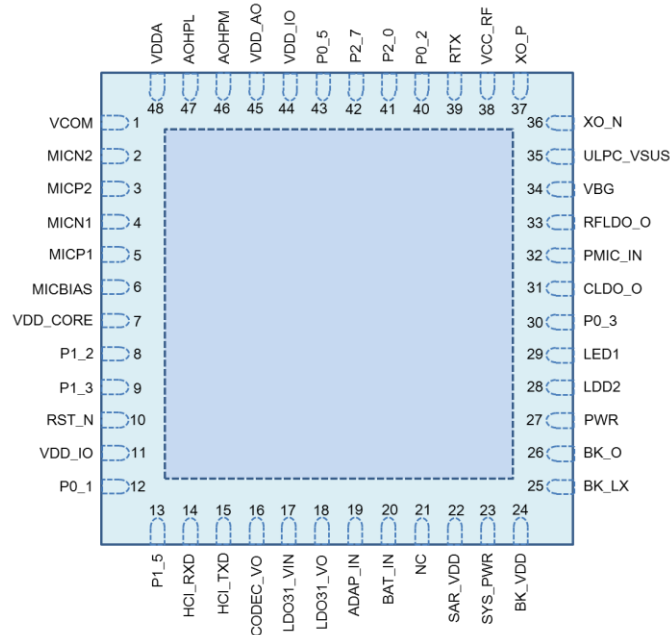
Feature \ Chip	IS2008S	IS2010S	IS2013S	IS2015S
Application	Headset	Headset	Speaker	Speaker
Stereo/Mono	Mono	Mono	Mono	Mono
Pin count	48	48	56	56
Dimension (mm ²)	6x6	6x6	7x7	7x7
Audio DAC output	1-ch	1-ch	1-ch	1-ch
DAC (single-end) SNR@2.8V (dB)	-98	-98	-98	-98
DAC (cap-less) SNR@2.8V (dB)	-96	-96	-96	-96
ADC SNR @2.8V (dB)	-90	-90	-90	-90
I ² S digital interface	X	X	X	X
Analog Aux- in	X	X	✓	✓
Mono MIC	2	2	1	1
Support external audio AMP	X	X	✓	✓
Build-in Class-D amplifier	X	X	1-ch	1-ch
UART	✓	✓	✓	✓
LED Driver	2	2	2	2
Internal DC-DC step-down regulator	✓	✓	✓	✓
DC 5V Adaptor Input	✓	✓	✓	✓
Battery Charger (350mA max)	✓	✓	✓	✓
GPIO for Application	6	6	9	9
Button support	6	6	6	6
Support NFC application	✓	✓	✓	✓
Voice prompt	✓	✓	✓	✓
Multi-tone	✓	✓	✓	✓
DSP sound effect	X	X	✓	✓
Profile				
HFP	1.6	1.6	1.6	1.6
AVRCP	1.5	1.5	1.5	1.5
A2DP	1.2	1.2	1.2	1.2
PBAP	1.0	1.0	1.0	1.0
HSP	1.1	1.1	1.1	1.1
SPP	X	1.0	X	1.0

Note: “✓” means support the feature
“X” means no support the feature.

3.0 PIN DESCRIPTION AND POWER SUPPLY

3.1 PIN ASSIGNMENT

TABLE 3-1: IS2008S/IS2010S PIN DESCRIPTION



Pin No.	Pin type	Name	Description
1	P	VCOM	Internal biasing voltage for CODEC
2	I	MICN2	Mic 2 mono differential analog negative input
3	I	MICP2	Mic 2 mono differential analog positive input
4	I	MICN1	Mic 1 mono differential analog negative input
5	I	MICP1	Mic 1 mono differential analog positive input
6	P	MICBIAS	Electric microphone biasing voltage
7	P	VDD_CORE	Core 1.2V power input; Connect to CLDO_O pin
8	O	P1_2	IO pin, default pull-high input EEPROM clock SCL
9	I/O	P1_3	IO pin, default pull-high input EEPROM data SDA
10	I	RST_N	System Reset Pin, active when rising edge.
11	P	VDD_IO	I/O power supply input (2.7~3.3V); Connect to LDO31_VO pin
12	I/O	P0_1	IO pin, default pull-high input (Note 1) 1. FWD key when class 2 RF (default), active low. 2. Class1 TX Control signal of external RF T/R switch, active high.
13	I/O	P1_5	IO pin, default pull-high input (Note 1) 1. NFC detection pin, active low. 2. Out_Ind_0 3. Slide Switch Detector, active low. 4. Buzzer Signal Output

Mono Audio SoC

Pin No.	Pin type	Name	Description
14	I	HCI_RXD	HCI-UART RX data
15	O	HCI_TXD	HCI-UART TX data
16	P	CODEC_VO	3.1V LDO output for CODEC power
17	P	LDO31_VIN	3.1V LDO input; Connect to SYS_PWR pin
18	P	LDO31_VO	3.1V LDO output
19	P	ADAP_IN	5V power adaptor input
20	P	BAT_IN	3.3~4.2V Li-ion battery input
21	-	NC	No Connection
22	P	SAR_VDD	SAR 1.8V input; Connect to BK_O pin
23	P	SYS_PWR	Power Output which come from BAT_IN or ADAP_IN
24	P	BK_VDD	1.8V buck VDD Power Input; Connect to SYS_PWR pin
25	P	BK_LX	1.8V buck pin for switch
26	P	BK_O	1.8V buck feedback input
27	I	PWR	Multi-Function Push Button and power on key
28	I	LED2	LED Driver 2
29	I	LED1	LED Driver 1
30	I/O	P0_3	IO pin, default pull-high input (Note 1) 1. REV key (default), active low. 2. Buzzer Signal Output 3. Out_Ind_1 4. Class1 RX Control signal of external RF T/R switch, active high.
31	P	CLDO_O	1.2V core LDO output
32	P	PMIC_IN	PMU blocks power input; Connect to BK_O pin
33	P	RFLDO_O	1.28V RF LDO output
34	P	VBG	Bandgap output reference for decoupling interference
35	P	ULPC_VSUS	ULPC 1.2V output power
36	I	XO_N	16MHz Crystal input negative
37	I	XO_P	16MHz Crystal input positive
38	P	VCC_RF	RF power input (1.28V) for both synthesizer and TX/RX block; Connect to RFLDO_O pin
39	I/O	RTX	RF RTX path
40	I	P0_2	IO pin, default pull-high input (Note 1) Play/Pause key (default), active low.
41	I	P2_0	IO pin, default pull-high input System Configuration, H: Application L: Baseband(IBDK Mode)
42	I	P2_7	IO pin, default pull-high input (Note 1) Volume up key (default), active low.
43	I	P0_5	IO pin, default pull-high input (Note 1) Volume down (default), active low.
44	P	VDD_IO	I/O power supply input (2.7~3.3V); Connect to LDO31_VO pin

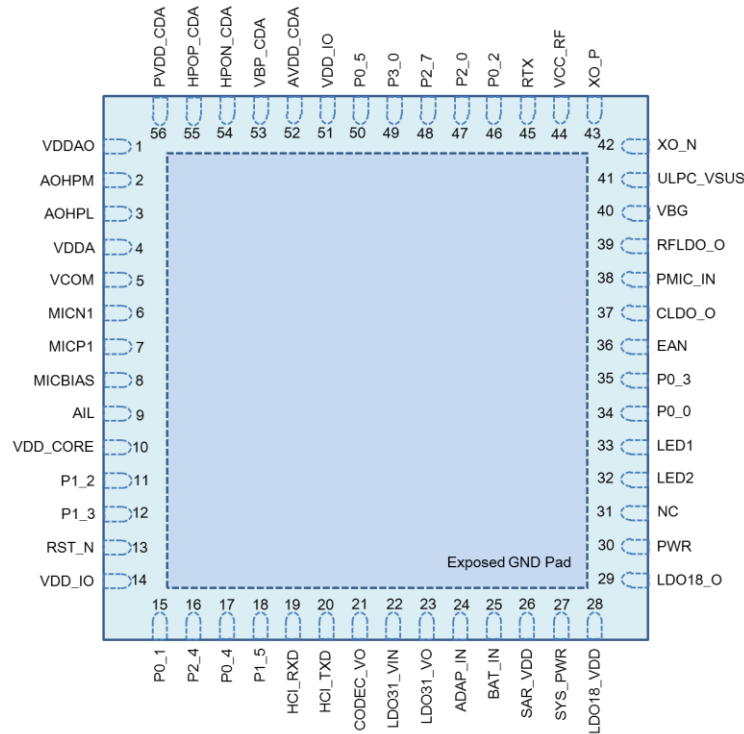
Mono Audio SoC

Pin No.	Pin type	Name	Description
45	P	VDDAO	Positive power supply dedicated to CODEC output amplifiers; Connect to CODEC_VO pin
46	O	AOHPM	Headphone common mode output/sense input.
47	O	AOHPL	L-channel analog headphone output
48	P	VDDA	Positive power supply/reference voltage for CODEC; Connect to CODEC_VO pin
49	P	EP	Exposed pad as ground

* I: signal input pin
* O: signal output pin
* I/O: signal input/output pin
* P: power pin

Note 1: These button or functions can be setup by “IS20XXS_UI” tool.

TABLE 3-2: IS2013S/IS2015S PIN DESCRIPTION



Pin No.	Pin type	Name	Description
1	P	VDDAO	Positive power supply dedicated to CODEC output amplifiers; Connect to CODEC_VO pin
2	O	AOHPM	Headphone common mode output/sense input.
3	O	AOHPL	L-channel analog headphone output
4	P	VDDA	Positive power supply/reference voltage for CODEC; Connect to CODEC_VO pin
5	P	VCOM	Internal biasing voltage for CODEC
6	I	MICN1	Mic 1 mono differential analog negative input
7	I	MICP1	Mic 1 mono differential analog positive input
8	P	MIC_BIAS	Electric microphone biasing voltage
9	I	AIL	L-channel single-ended analog inputs
10	P	VDD_CORE	Core 1.2V power input; Connect to CLDO_O pin
11	O	P1_2	IO pin, default pull-high input EEPROM clock SCL
12	I/O	P1_3	IO pin, default pull-high input EEPROM data SDA
13	I	RST_N	System Reset Pin, active when rising edge.
14	P	VDD_IO	I/O power supply input (2.7~3.3V); Connect to LDO31_VO pin
15	I/O	P0_1	IO pin, default pull-high input (Note 1) 1. FWD key when class 2 RF (default), active low. 2. Class1 TX Control signal of external RF T/R switch, active high.

Mono Audio SoC

Pin No.	Pin type	Name	Description
16	I	P2_4	IO pin, default pull-high input System Configuration, L: Boot Mode with P2_0 low combination
17	I/O	P0_4	IO pin, default pull-high input. (Note 1) 1. NFC detection pin, active low. 2. Out_Ind_0
18	I/O	P1_5	IO pin, default pull-high input (Note 1) 1. NFC detection pin, active low. 2. Out_Ind_0 3. Slide Switch Detector, active low. 4. Buzzer Signal Output
19	I	HCI_RXD	HCI-UART RX data
20	O	HCI_TXD	HCI-UART TX data
21	P	CODEC_VO	3.1V LDO output for CODEC power
22	P	LDO31_VIN	3.1V LDO input; Connect to SYS_PWR pin
23	P	LDO31_VO	3.1V LDO output
24	P	ADAP_IN	5V power adaptor input
25	P	BAT_IN	3.3~4.2V Li-Ion battery input
26	P	SAR_VDD	SAR 1.8V input; Connect to BK_O pin
27	P	SYS_PWR	Power Output which come from BAT_IN or ADAP_IN
28	P	LDO18_VDD	1.8V LDO VDD Power Input; Connect to SYS_PWR pin
29	P	LDO18_O	1.8V LDO output
30	I	PWR	Multi-Function Push Button and power on key
31	-	NC	No Connection
32	I	LED2	LED Driver 2
33	I	LED1	LED Driver 1
34	I/O	P0_0	IO pin, default pull-high input (Note 1) 1. Slide Switch Detector, active low. 2. UART TX_IND, active low.
35	I/O	P0_3	IO pin, default pull-high input (Note 1) 1. REV key (default), active low. 2. Buzzer Signal Output 3. Out_Ind_1 4. Class1 RX Control signal of external RF T/R switch, active high.
36	I	EAN	Embedded ROM/External Flash enable H: Embedded; L: External Flash
37	P	CLDO_O	1.2V core LDO output
38	P	PMIC_IN	PMU blocks power input; Connect to BK_O pin
39	P	RFLDO_O	1.28V RF LDO output
40	P	VBG	Bandgap output reference for decoupling interference
41	P	ULPC_VSUS	ULPC 1.2V output power
42	I	XO_N	16MHz Crystal input negative
43	I	XO_P	16MHz Crystal input positive

Mono Audio SoC

Pin No.	Pin type	Name	Description
44	P	VCC_RF	RF power input (1.28V) for both synthesizer and TX/RX block; Connect to RFLDO_O pin
45	I/O	RTX	RF RTX path
46	I	P0_2	IO pin, default pull-high input (Note 1) Play/Pause key (default), active low.
47	I	P2_0	IO pin, default pull-high input System Configuration, H: Application L: Baseband(IBDK Mode)
48	I	P2_7	IO pin, default pull-high input (Note 1) Volume up key (default), active low.
49	I	P3_0	IO pin, default pull-high input (Note 1) Line-in Detector (default), active low.
50	I	P0_5	IO pin, default pull-high input (Note 1) Volume down (default), active low.
51	P	VDD_IO	I/O power supply input (2.7~3.3V); Connect to LDO31_VO pin
52	P	AVDD_CDA	Supply voltage of audio amplifier.
53	P	VBP_CDA	Reference voltage output.
54	O	HPON_CDA	Negative BTL output of channel-1
55	O	HPOP_CDA	Positive BTL output of channel-1
56	P	PVDD_CDA	Supply voltage of power stage ch-1
57	P	EP	Exposed pad as ground

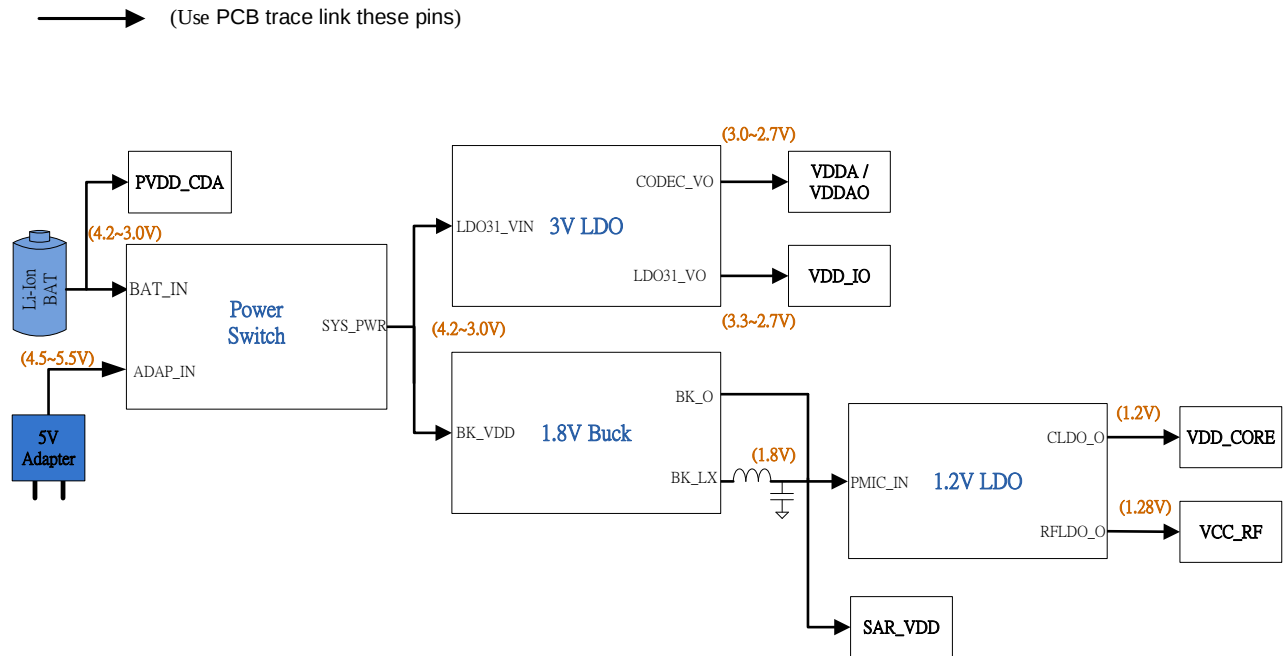
* I: signal input pin
* O: signal output pin
* I/O: signal input/output pin
* P: power pin

Note 1: These button or functions can be setup by “IS20XXS_UI” tool.

3.2 POWER SUPPLY

The device is powered via BAT pin input. If a battery is not connected, an external power supply needs to provide to this input. Figure 3-1 shows the PCB connections from BAT pin to other voltage supply pins of the chip.

FIGURE 3-1: POWER TREE DIAGRAM



4.0 TRANSCEIVER

The mono audio chip is designed and optimized for Bluetooth 2.4 GHz system. It contains a complete radio frequency transmitter/receiver section. An internal synthesizer generates a stable clock for synchronize with another device.

4.1 TRANSMITTER

The internal PA has a maximum output power of +4dBm with 20dB power level control. This is applied into Class2/3 radios without external RF PA.

The transmitter directly performs IQ conversion to minimize the frequency drift, and it can excess 20dB power range with temperature compensation mechanism.

4.2 RECEVIER

The LNA operates with TR-combined mode for single port application. It can save a pin on package and without an external TX/RX switch.

The ADC is utilized to sample the input analog wave and convert into digital signal for de-modulator analysis. A channel filter has been integrated into receiver channel before the ADC, which to reduce the external component count and increase the anti-interference capability.

The image rejection filter is used to reject image frequency for low-IF architecture. This filter for low-IF architecture is intent to reduce external BPF component for super heterodyne architecture.

RSSI signal is feedback to the processor to control the RF output power to make a good tradeoff for effective distance and current consumption.

4.3 SYNTHESIZER

A synthesizer generates a clock for radio transceiver operation. There is a VCO inside with tunable internal LC tank. It can reduce variation for components. A crystal oscillation with internal digital trimming circuit provides a stable clock for synthesizer.

4.4 MODEM

For Bluetooth v1.2 specification and below, 1 Mbps was the standard data rate based on Gaussian Frequency Shift Keying (GFSK) modulation scheme. This basic rate modem meets BDR requirements of Bluetooth v2.0 with EDR specification.

For Bluetooth v2.0 with EDR specification, Enhanced Data Rate (EDR) has been introduced to provide 2 and 3 Mbps data rates as well as 1 Mbps. This enhanced data rate modem meets EDR requirements of Bluetooth v2.0 with EDR specification. For the viewpoint of baseband, both BDR and EDR utilize the same 1MHz symbol rate and 1.6 KHz slot rate. For BDR, 1 symbol represents 1 bit. However each symbol in the payload part of EDR packets represents 2 or 3 bits. This is achieved by using two different modulations, $\pi/4$ DQPSK and 8DPSK.

4.5 AFH (Adaptive Frequency Hopping)

Stereo audio chip have AFH function to avoid RF interference. It has an algorithm to check the interference nearby and choice clear channel to transceiver Bluetooth signal.

5.0 MICROPROCESSOR

A single-cycle 8-bit MCU is built into the mono audio chip to execute the Bluetooth protocols. It operates from 16MHz to higher frequency where the firmware can dynamically adjust the tradeoff between the computing power and the power consumption. The MCU firmware is hard-wired in ROM to minimize the firmware execution power consumption and to save the external flash cost.

5.1 MEMORY

A synchronous single port RAM interface is used. There are sufficient ROM and RAM to fulfill the requirement of processor. A register bank, a dedicated single port memory and a flash memory are connected to the processor bus. The processor coordinates all the link control procedures and data movement using a set of pointers registers.

5.2 EXTERNAL RESET

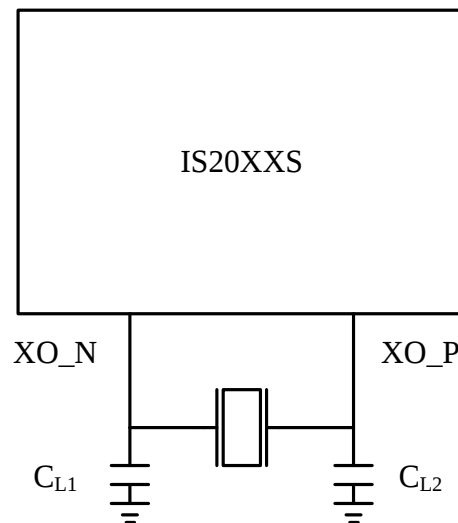
The chip provides a watchdog timer to reset the chip. It has an integrated Power-On Reset (POR) circuit that resets all circuits to a known power-on state. This action can also be driven by an external reset signal that can be used to externally control the device, forcing it into a power-on reset state. The RST signal input is active low and no connection is required in most applications.

5.3 REFERENCE CLOCK

Mono audio chip is composed of an integrated crystal oscillation function. It uses a 16 MHz external crystal and two specified loading capacitors to provide a high quality system reference timer source. This feature is typically used to remove the initial tolerance frequency errors associated with the crystal and its equivalent loading capacitance in mass production. Frequency trim is achieved by adjusting the crystal loading capacitance through the on-chip trim capacitors C_{trim} .

The value of trimming capacitance is around 200fF (200×10^{-15} F) per LSB at 5 bits word, therefore the overall adjustable clock frequency is around 40 KHz.

FIGURE 5-1: CRYSTAL CONNECTION



$$C_{trim} = 200\text{fF} * (1 \sim 31) ; C_{int} \approx 3\text{pF}$$

$$C_L = [(C_{L1} * C_{L2}) / (C_{L1} + C_{L2})] + (C_{trim} / 2) + C_{int}$$

(e.g. Set trim value as 16, then $C_{trim} = 3.2\text{pF}$.)

For a 16M Hz crystal which $C_L = 9\text{pF}$, we can get $C_{L1} = C_{L2} = 9.1\text{pF}$ in this case.)

For C_L selection, please refer to the datasheet of crystal vendor

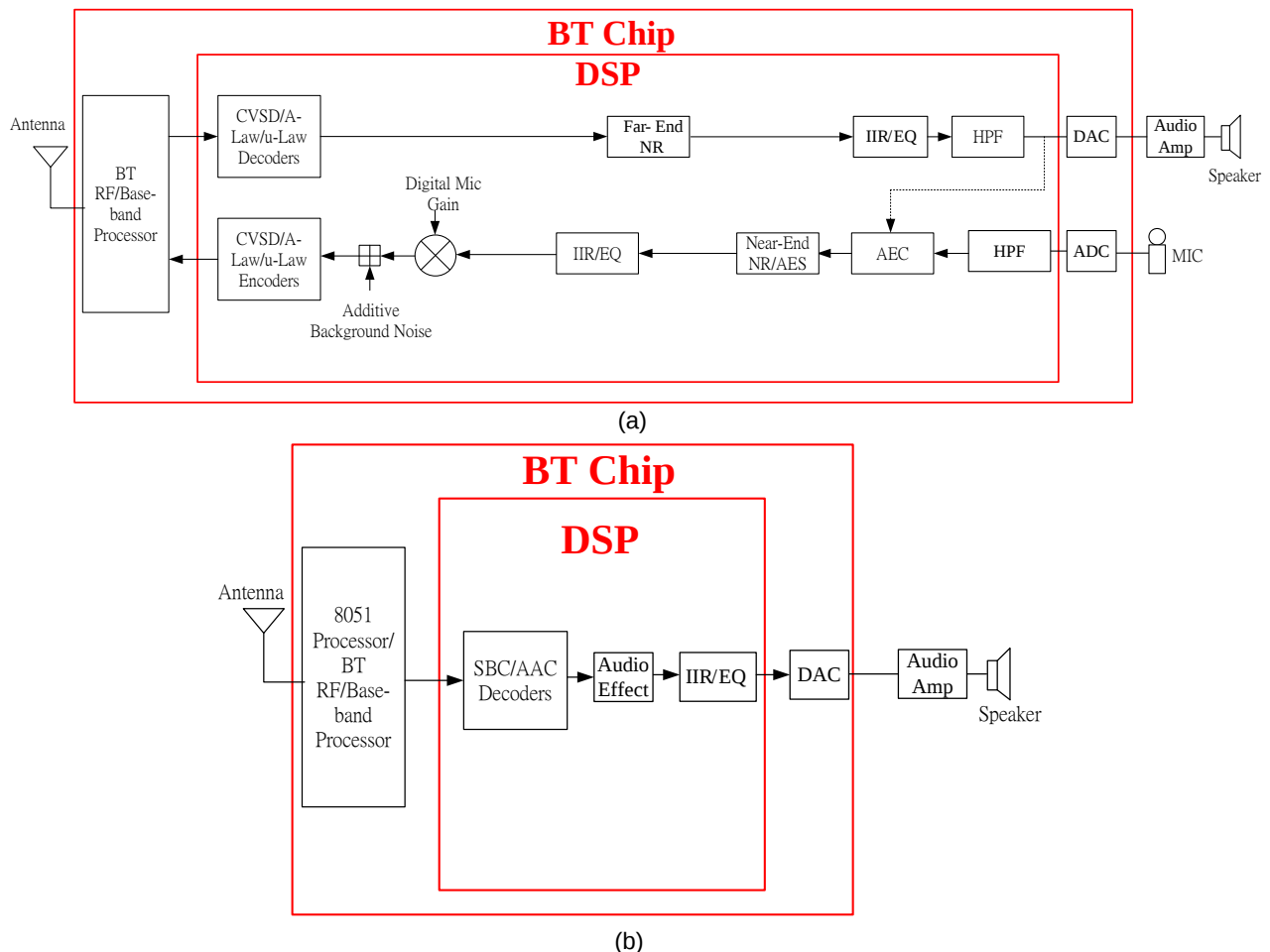
6.0 AUDIO

There are a few stages for input audio and output audio. Each stage can be programmed to vary the gain response characteristics. For microphone input, both single-end input and differential input are supported. One of the important points in maintaining a high quality signal is to provide a stable bias voltage source to the condenser microphone's FET. DC blocking capacitors may be used at both positive and negative sides of input. Internally, this analog signal is converted to 16-bit 8 kHz linear PCM data.

6.1 DIGITAL SIGNAL PROCESSOR

A digital signal processor (DSP) cooperates with MCU to perform digital audio processing with some advanced features such as noise cancellation, audio output level suppression and etc. It provides audio processing with some advanced features. The DSP cancels the acoustic echo that may present in headset or speaker. All the audio processing is performed by the DSP with low power consumption. This technique effectively cancels the incoming echo signal without impact to the desired voice signal. An outgoing signal to the speaker which level exceeds the threshold (and therefore deemed likely to create echo) will be result in suppression of the signal along the input path from the microphone. Filtering is also applied to provide a smoother transition for more natural user experience.

FIGURE 6-1: BLOCK DIAGRAM OF DSP



Processing flow of speakerphone applications for (a) speech and (b) audio signal processing.

There is a "DSPTool_IS20XX" can support user to set up these DSP parameter. For more detail information, please reference "BT5502_DSP_APP" document.

6.2 CLASS-D AUDIO AMPLIFIER

The class D amplifier has significant advantage in many applications because of its lower power dissipation which produces less heat. IS2013S and IS2015S chip has built-in a class D amplifier that reduces circuit board space and system cost. The efficiency of the amplifier extends the battery life in portable systems.

The class D amplifier is implemented by using a full-bridge output stage. A full bridge uses two half-bridge stages to drive the load differentially. It provides a good signal to noise ratio (SNR) and enough drive capability for a 4 Ohm speaker driver.

6.3 CODEC

The built-in codec has a high Signal to Noise ratio performance. This built-in codec consist of an analog to digital converter (ADC), a digital to analog converter (DAC) and additional analog circuitry.

6.4 LINE IN (Aux In)

The chip supports one analog line in from external audio source. The analog line in signal can be processed by the DSP to generate different sound effect (Multi-band Dynamic Range Compression, Audio Widening). The sound effect can be set up by DSP tool.

7.0 POWER MANAGEMENT UNIT

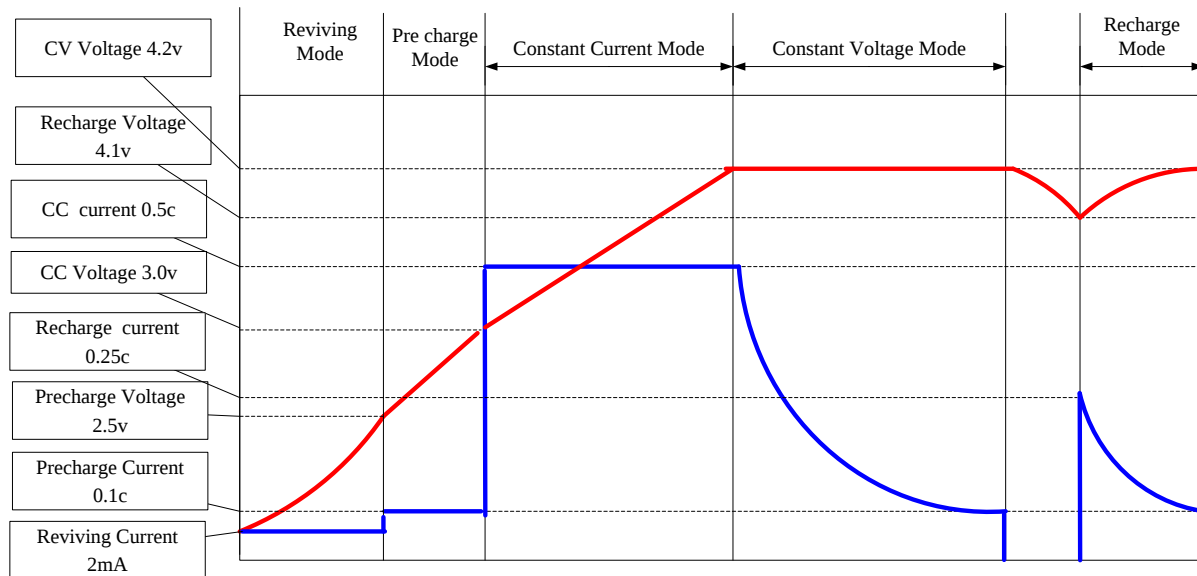
The on-chip Power management Unit (PMU) has two main feature; Lithium Ion battery charging and voltage regulation. A power switch is used to switch over the power source between battery and adaptor automatically. The PMU also provides driving current for 2 LEDs.

7.1 CHARGING A BATTERY

Mono audio chip has a built-in battery charger which is optimized for lithium polymer batteries. The charger includes a current sensor for charging control, user programmable current regulation and high accuracy voltage regulation.

The charging current parameters are configured by "IS20XXS_UI" tool. Whenever the adaptor is plug-in, the charging circuit will be activated. Reviving, Pre-charging, Constant Current and Constant Voltage modes are implemented and re-charging function is also included. The maximum charging current is 350mA.

FIGURE 7-1: CHARGING CURVE



7.2 VOLTAGE MONITORING

A 10-bit Successive-Approximation-Register analog to digital converter (SAR ADC) provides one dedicated channel for battery voltage level detection. The warning level is programmable by "IS20XXS_UI" tool. This ADC provides a good resolution that MCU can control the charging process.

7.3 LDO

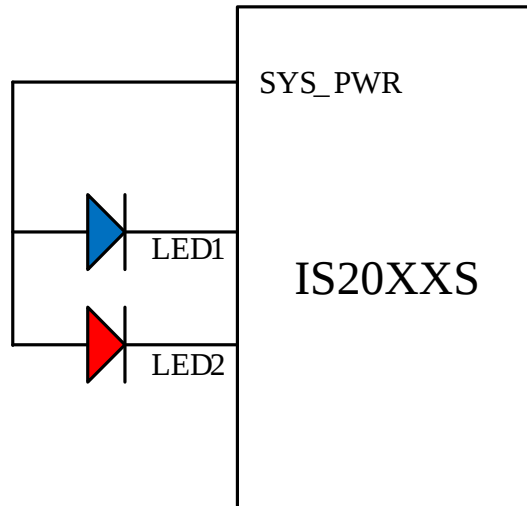
The built-in LDO is used to convert the battery or adaptor power for power supply. It also integrates hardware architecture to control power on/off procedure. The built-in programmable LDOs provide power for codec and digital IO pads. It is used to buffer the high input voltage from battery or adapter. This LDO needs 1uF bypass capacitor.

7.4 SWITCHING REGULATOR

The built-in programmable output voltage regulator can convert battery voltage for RF and baseband core power supply. This converter has high conversion efficiency and fast transient response.

7.5 LED DRIVER

There are two dedicate LED drivers to control the LEDs. They provide enough sink current (16 step control and 0.35mA for each step) that LED can be connected directly with IS20XXS. LED setting can be set up by "IS20XXS_UI" tool.



8.0 GENERAL PURPOSE IOS

Stereo audio chip provides six IOS for key functions. The corresponding key functions can be set up by "IS20XXS_UI" tool. The first button (Button 0) must be power key. The power on/off functions only can be set on PWR pin. There are four different operations (short click, long click, double click and combinations) for every button can be defined as different functions. All these function can be set up by "IS20XXS_UI" tool.

IO Pin for Buttons

Button Name	Default Functions	IO pin name
Button 0	Power / MFB	PWR
Button 1	PLAY/PAUSE	P0_2
Button 2	Volume UP	P2_7
Button 3	Volume DOWN	P0_5
Button 4	FWD	P0_1
Button 5	REV	P0_3

Note: All these function can be set up by "IS20XXS_UI" tool.

Some signals were generated to indicate or control outside devices. The most popular applications are NFC for easy pairing, external audio amplifier for louder speaker and buzzer for indication.

IOS pin for added functions

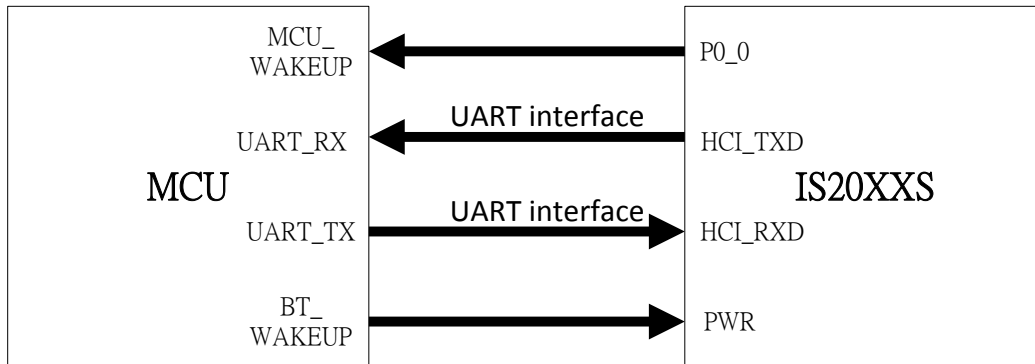
Functions	IO configurable features
Slide switch	P0_0 / P1_5
Buzzer	P0_3
NFC detect	P0_4 / P1_5
External AMP enable	P1_5

Note: All these function can be set up by "IS20XXS_UI" tool.

9.0 OPERATION WITH EXTERNAL MCU

IS20XXS support UART command set to make an external MCU to control IS20XXS chip. Here is the connection interface between IS20XXS and MCU.

FIGURE 9-1: INTERFACE BETWEEN MCU AND IS20XX CHIP



MCU can control IS20XXS chip by UART interface and wakeup IS20XXS by PWR pin. IS20XXS provide wakeup MCU function by connect to P0_0 pin of IS20XX.

“UART_CommandSet_v154” document provide all UART command which IS20XX support and “IS20XXS_UI” tool will help you to set up your system support UART command.

For more detail description, please reference “UART_CommandSet_v154” document and “IS20XXS_UI” tool.

9.1 TIMING SEQUENCE OF UART APPLICATION

FIGURE 9-2: POWER ON/OFF SEQUENCE

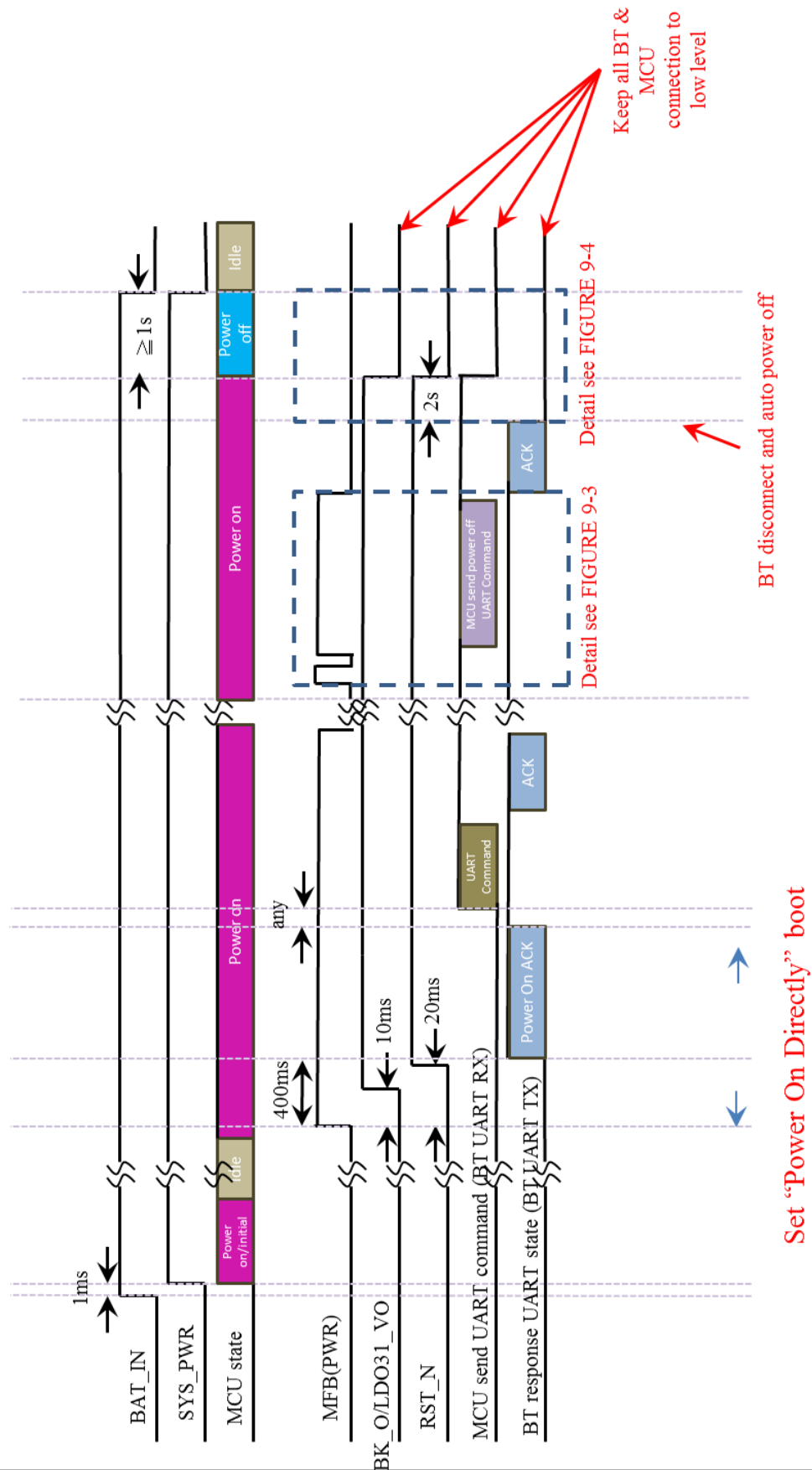


FIGURE 9-3: TIMING SEQUENCE OF RX INDICATION AFTER POWER ON

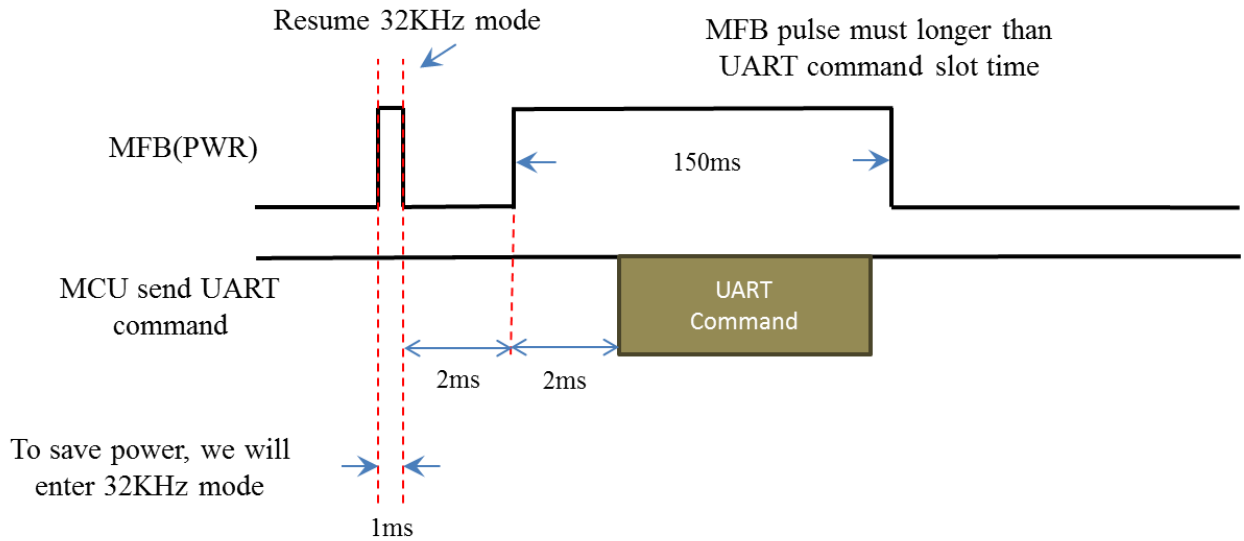
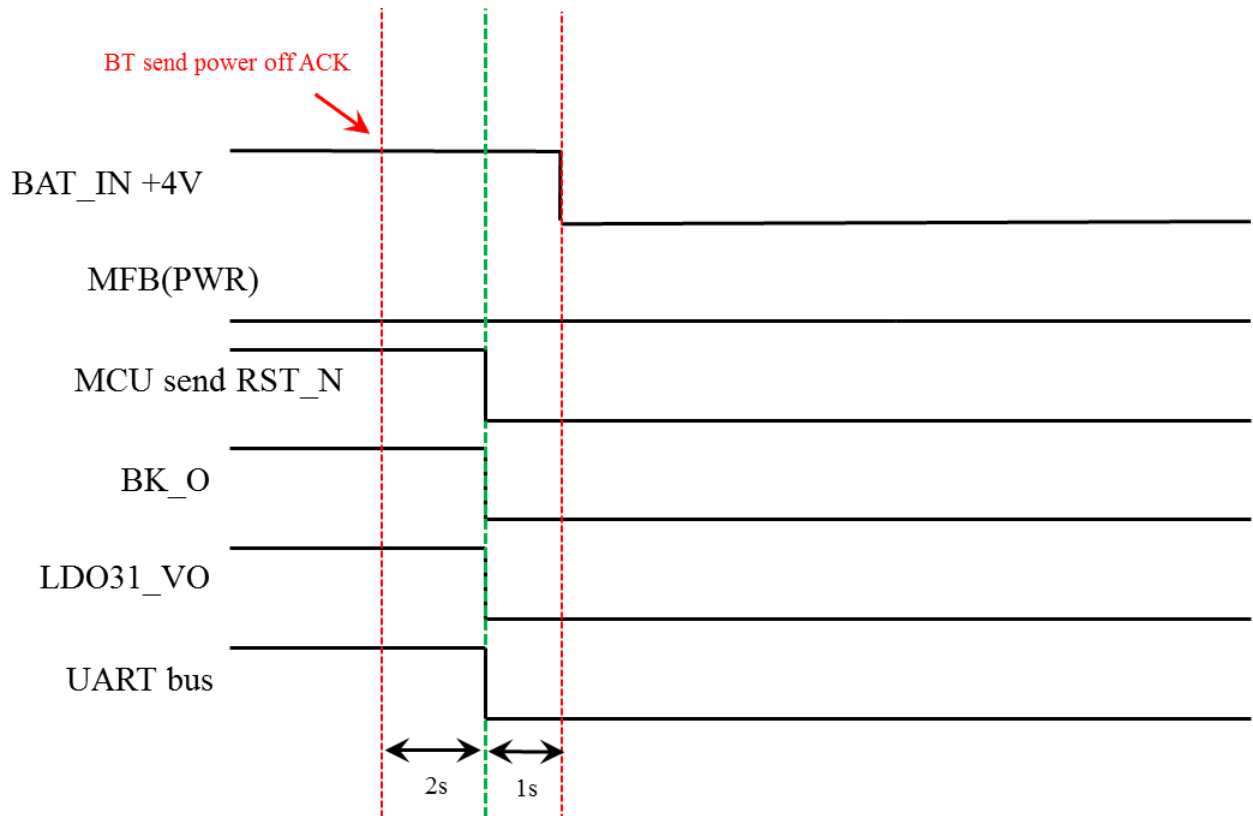


FIGURE 9-4: TIMING SEQUENCE OF POWER OFF

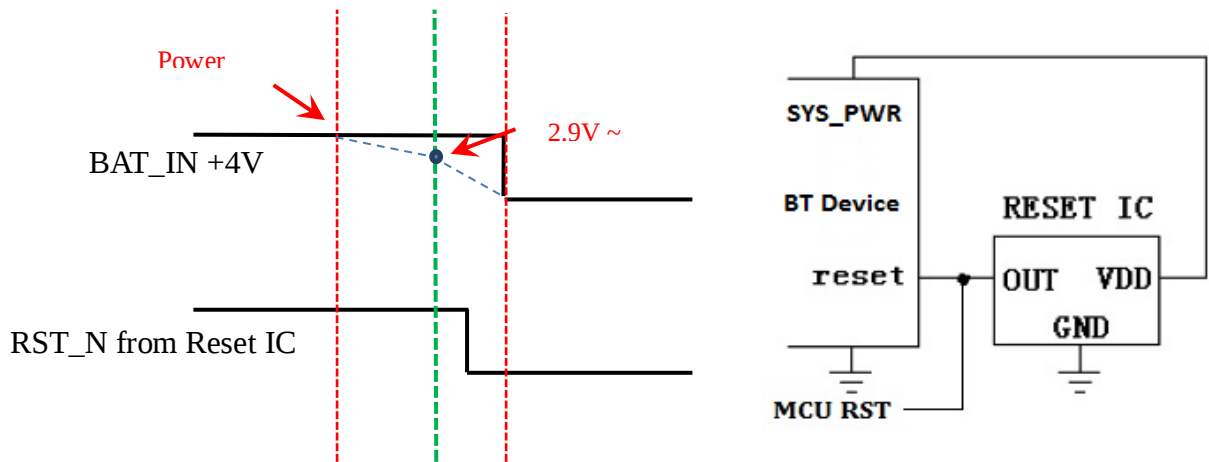


EEPROM clock= 100KHz

For a byte write, $0.01\text{ms} \times 32\text{clock} \times 2 = 640\text{us}$

If power drop faster than 640us, some issue may occurs, but the possibility is low

FIGURE 9-7: TIMING SEQUENCE OF POWER DROP PROTECTION



If BT's BAT use adaptor translates voltage by LDO, we recommend use "Reset IC" to avoid power off suddenly. Rest IC spec output pin must be "Open Drain", delay time $\leq 10\text{ms}$

Recommend part: TCM809SVNB713 or G691L263T73

10.0 ANTENNA PLACEMENT RULE

For Bluetooth product, antenna placement will affect whole system performance. Antenna need free space to transmit RF signal, it can't be surround by GND plane.

Here are some examples of good and poor placement on a Main application board with GND plane.

FIGURE 10-1: ANTENNA PLACEMENT EXAMPLES

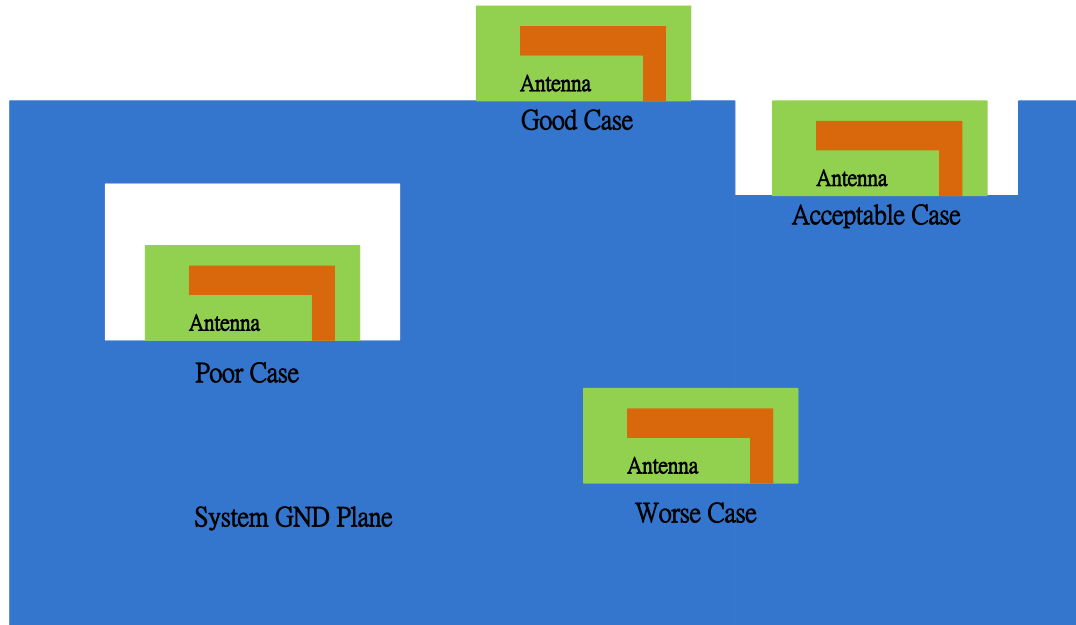
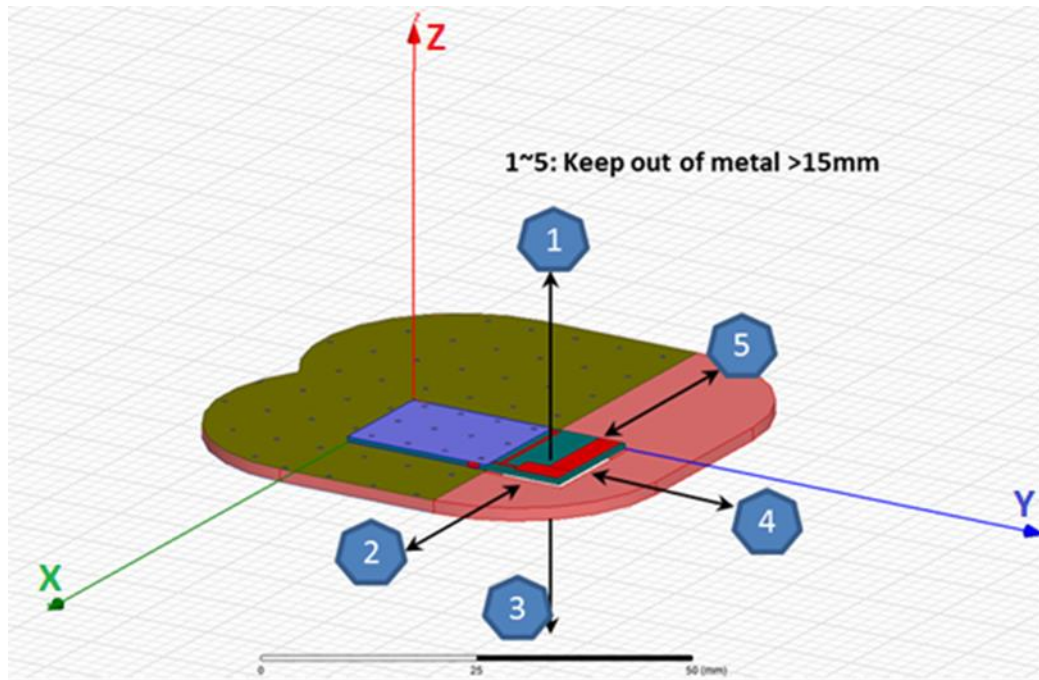


FIGURE 10-2: KEEP OUT AREA SUGGESTION FOR ANTENNA



For more detail free space of antenna placement design, you can reference the design rule of antenna produce vendor.

11.0 SPECIFICATIONS

Table 11-1: ABSOLUTE MAXIMUM SPECIFICATION

Symbol	Parameter	Min	Max	Unit
VDD_CORE	Digital core supply voltage	0	1.35	V
VCC_RF	RF supply voltage	0	1.35	V
SAR_VDD	SAR ADC supply voltage	0	2.1	V
VDDA/VDDAO	CODEC supply voltage	0	3.3	V
VDD_IO	I/O supply voltage	0	3.6	V
BK_VDD	BUCK supply voltage	0	4.3	V
LDO31_VIN	Supply voltage	0	4.3	V
BAT_IN	Input voltage for battery	0	4.3	V
ADAP_IN	Input voltage for adaptor	0	7.0	V
T _{STORE}	Storage temperature	-65	+150	°C
T _{OPERATION}	Operation temperature	-20	+70	°C

Table 11-2: RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min	Typical	Max	Unit
VDD_CORE	Digital core supply voltage	1.14	1.2	1.26	V
VCC_RF	RF supply voltage	1.22	1.28	1.34	V
SAR_VDD	SAR ADC supply voltage	1.62	1.8	1.98	V
VDDA/VDDAO	CODEC supply voltage	2.7	2.8	3.0	V
VDD_IO	I/O supply voltage	2.7	3.0	3.3	V
BK_VDD	1.8V BUCK supply voltage	3	3.7	4.25	V
LDO31_VIN	3V LDO supply voltage	3	3.7	4.25	V
BAT_IN	Input voltage for battery	3	3.7	4.25	V
ADAP_IN	Input voltage for adaptor	4.5	5	5.5	V
T _{OPERATION}	Operation temperature	-20	+25	+70	°C

Note:

All these supply voltage are programmable by EEPROM parameters.

Mono Audio SoC

Table 11-3: BUCK SWITCHING REGULATOR

Parameter	Min	Typical	Max	Unit
Input Voltage	3.0	3.7	4.25	V
Output Voltage ($I_{load}=70mA$, $V_{in}=4V$)	1.7	1.8	2.05	V
Output Voltage Accuracy		± 5		%
Output Voltage Adjustable Step		50		mV/Step
Output Adjustment Range	-0.1		+0.25	V
Average Load Current (I_{LOAD})	120			mA
Conversion efficiency (BAT=3.8V, $I_{load} = 50mA$)		88		%
Quiescent Current (PFM)			40	μA
Output Current (peak)	200			mA
Shutdown Current			<1	μA

Note:

- (1) Test condition: SAR_VDD=1.8V, temperature=25 °C.
- (2) These parameters are characterized but not tested in manufacturing.

Table 11-4: LOW DROP REGULATOR

Parameter	Min	Typical	Max	Unit
Input Voltage	3.0	3.7	4.25	V
Output Voltage	$V_{OUT CODEC}$	2.8		V
	$V_{OUT IO}$	2.8		
Output Accuracy ($V_{IN}=3.7V$, $I_{LOAD}=100mA$, 27°C)		± 5		%
Output current (average)			100	mA
Drop-out voltage ($I_{load} = \text{maximum output current}$)			300	mV
Quiescent Current (excluding load, $I_{load} < 1mA$)		45		μA
Shutdown Current			<1	μA

Note:

- (1) Test condition: SAR_VDD=1.8V, temperature=25 °C.
- (2) These parameters are characterized but not tested in manufacturing.

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Table 11-5: BATTERY CHARGER

Parameter		Min	Typical	Max	Unit
Input Voltage		4.5	5.0	5.5	V
Supply current to charger only			3	4.5	mA
Maximum Battery Fast Charge Current Note: ENX2=0	Headroom > 0.7V (ADAP_IN=5V)	170	200	240	mA
	Headroom = 0.3V (ADAP_IN=4.5V)	160	180	240	mA
Maximum Battery Fast Charge Current Note: ENX2=1	Headroom > 0.7V (ADAP_IN=5V)	330	350	420	mA
	Headroom = 0.3V (ADAP_IN=4.5V)	180	220	270	mA
Trickle Charge Voltage Threshold			3		V
Battery Charge Termination Current, (% of Fast Charge Current)			10		%

Note:

- (1) Headroom = $V_{ADAP_IN} - V_{BAT}$
- (2) ENX2 is not allowed to be enabled when $V_{ADAP_IN} - V_{BAT} > 2V$
- (3) These parameters are characterized but not tested in manufacturing.

Table 11-6: LED DRIVER

Parameter	Min	Typical	Max	Unit
Open-drain Voltage			3.6	V
Programmable Current Range	0		5.25	mA
Intensity Control		16		step
Current Step		0.35		mA
Power Down Open-drain Current			1	μA
Shutdown Current			1	μA

Note:

- (1) Test condition: SAR_VDD=1.8V, temperature=25 °C.
- (2) These parameters are characterized but not tested in manufacturing.

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Table 11-7: AUDIO CODEC DIGITAL TO ANALOGUE CONVERTER

T= 25°C, V _{dd} =3.0V, 1KHz sine wave input, Bandwidth = 20Hz~20KHz					
Parameter (Condition)		Min.	Typ.	Max.	Unit
Over-sampling rate			128		f _s
Resolution		16		20	Bits
Output Sample Rate		8		48	KHz
Signal to Noise Ratio Note: 1 (SNR @cap-less mode) for 48kHz			96		dB
Signal to Noise Ratio Note: 1 (SNR @single-end mode) for 48kHz			98		dB
Digital Gain		-54		4.85	dB
Digital Gain Resolution			2~6		dB
Analog Gain		-28		3	dB
Analog Gain Resolution			1		dB
Output Voltage Full-scale Swing (AVDD=2.8V)		495	742.5		mV rms
Maximum Output Power (16Ω load)			34.5		mW
Maximum Output Power (32Ω load)			17.2		mW
Allowed Load	Resistive	8	16	O.C.	Ω
	Capacitive			500	pF
THD+N (16Ω load)				0.05	%
Signal to Noise Ratio (SNR @ 16Ω load)				96	dB

Note:

- (1) f_{in}=1KHz, B/W=20~20KHz, A-weighted, THD+N < 0.01%, 0dBFS signal, Load=100KΩ
- (2) These parameters are characterized but not tested in manufacturing.

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Table 11-8: Audio codec Analogue to Digital Converter

T= 25°C, V_{dd}=3.0V, 1KHz sine wave input, Bandwidth = 20Hz~20KHz

Parameter (Condition)	Min.	Typ.	Max.	Unit
Resolution			16	Bits
Output Sample Rate	8		48	KHz
Signal to Noise Ratio Note: 1 (SNR @MIC or Line-in mode)		90		dB
Digital Gain	-54		4.85	dB
Digital Gain Resolution		2~6		dB
MIC Boost Gain		20		dB
Analog Gain			60	dB
Analog Gain Resolution		2.0		dB
Input full-scale at maximum gain (differential)		4		mV rms
Input full-scale at minimum gain (differential)		800		mV rms
3dB bandwidth		20		KHz
Microphone mode (input impedance)		24		K Ω
THD+N (microphone input) @30mVrms input		0.02		%

Note:

- (1) f_{in} =1KHz, B/W=20~20KHz, A-weighted, THD+N < 1%, 150mV_{pp} input
- (2) These parameters are characterized but not tested in manufacturing.

Table 11-9: SINGLE-CHANNEL CLASS-D AMPLIFIER

Parameter (Condition)		Min.	Typ.	Max.	Unit
Standalone SNR (A-weighting)			100		dB
Gain			12		dB
PSRR (217Hz, 200mV on PVDD)			70		dB
Efficiency	4ohm	80		85	%
	8ohm	85		90	%
Supply Voltage		3.0	3.7	4.5	V
Load			4		ohm
Quiescent current (1 channel)			2		mA
Sample frequency			250		KHz
Over current limits			2.3		A
Shutdown current			1.0		uA

Note:

(1) Test condition: PVDD_CDA=4.2V, temperature=25 °C.

(2) These parameters are characterized but not tested in manufacturing.

Table 11-10: SYSTEM CURRENT CONSUMPTION

System Status	Typ.	Max.	Unit
System Off Mode	2	5	uA
Standby Mode	0.8		mA
Linked Mode	0.4		mA
SCO Link	7.8		mA
A2DP Link (V _{p-p} =200mV; 1k tone signal)	10.7		mA

Note: Use IS2010 EVB as test platform.

Test condition: BAT_IN= 3.8V, link with HTC EYE cell phone.

Mono Audio SoC

Table 11-11: TRANSMITTER SECTION FOR BDR and EDR

Parameter	Min	Typ	Max	Bluetooth specification	Unit
Maximum RF transmit power		3.0	4.0	-6 to 4	dBm
Relative transmit power	-4	-1.2	1	-4 to 1	dB

Note:

The RF Transmit power is calibrated during production using MP Tool software and MT8852 Bluetooth Test equipment.
Test condition: VCC_RF= 1.28V, temperature=25 °C.

Table 11-12: RECEIVER SECTION FOR BDR and EDR

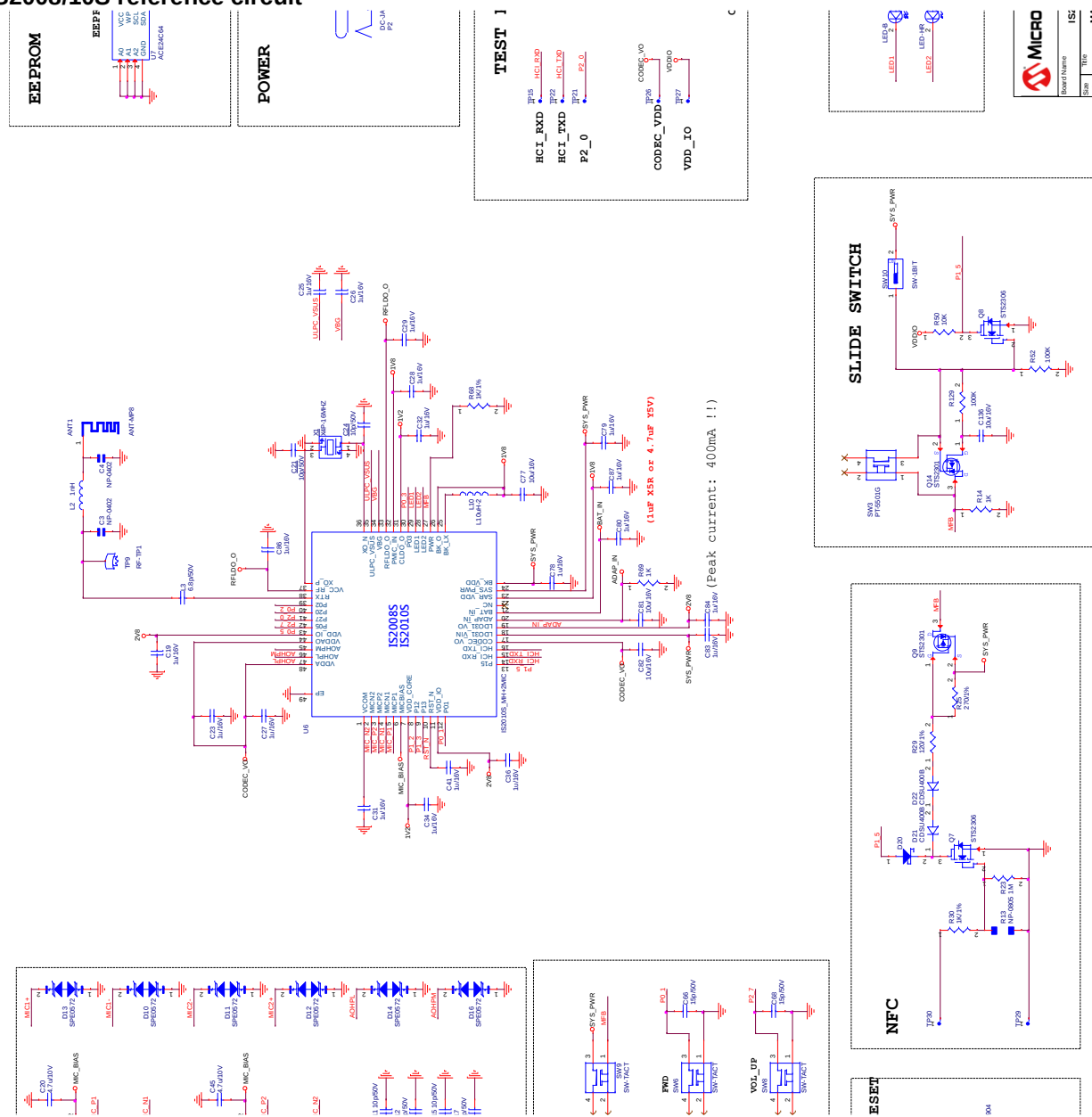
	Modulation	Min	Typ	Max	Bluetooth specification	Unit
Sensitivity at 0.1% BER	GFSK		-90		≤ -70	dBm
Sensitivity at 0.01% BER	$\pi/4$ DQPSK		-91		≤ -70	dBm
	8DPSK		-82		≤ -70	dBm

Note:

- (1) Test condition: VCC_RF= 1.28V, temperature=25 °C.
- (2) These parameters are characterized but not tested in manufacturing.

12.0 REFERENCE CIRCUIT

FIGURE 12-1: IS2008/10S reference circuit



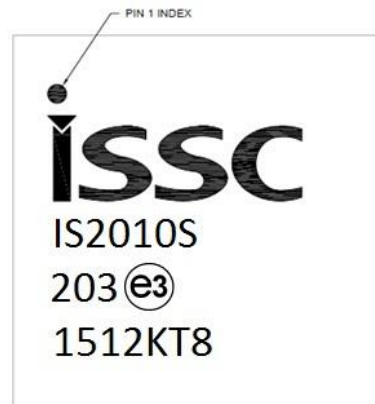
- b) IS2010S-203: 203 version ROM code IS2010 chip in QFN type package.

13.2 PACKAGE MARKING INFORMATION

48 Lead QFN (6x6x0.9 mm)



Example



56 Lead QFN (7x7x0.9 mm)

Example



Legend:

XXX: Chip serial number version and (e3) Pb-free JEDEC designator for Matte Tin (Sn)

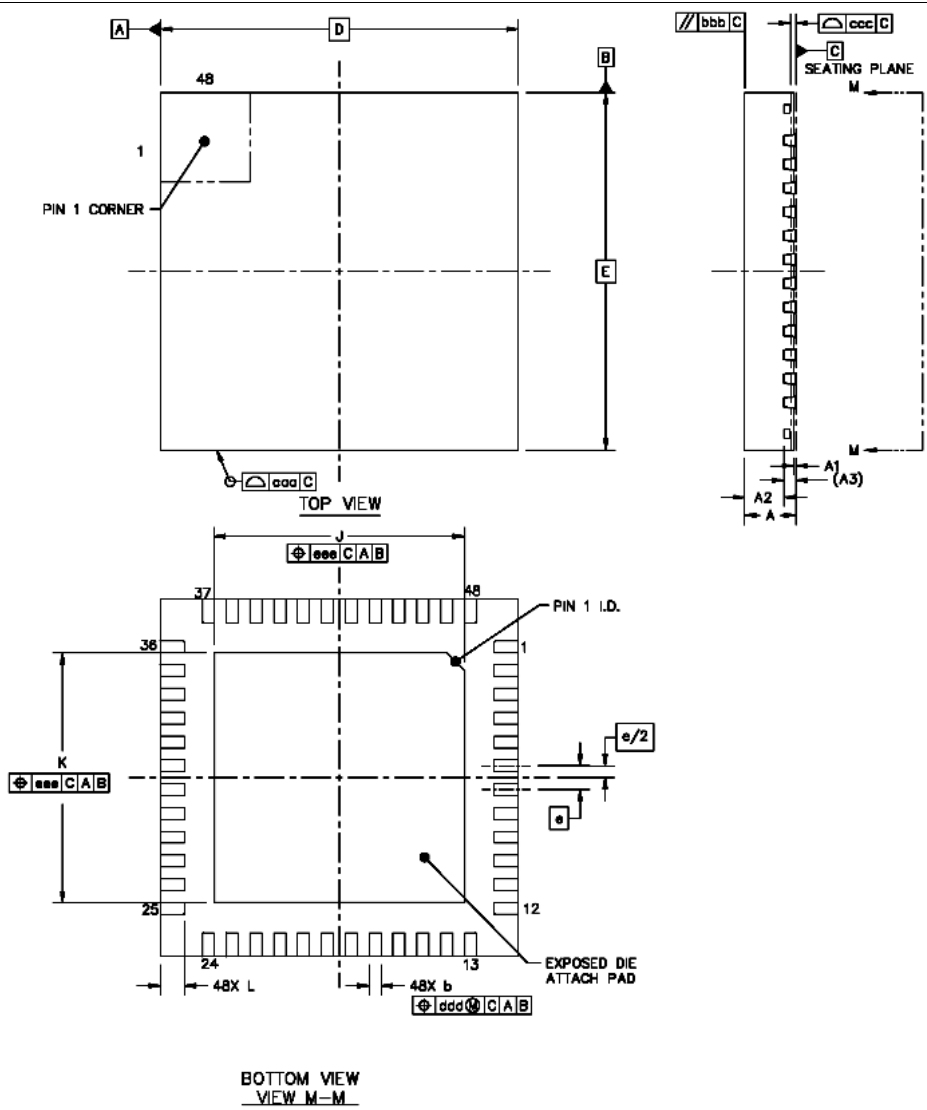
YY: Year code (last 2 digits of calendar year)

WW: Week code (week of January 1 is week "1")

NNN: Alphanumeric traceability code

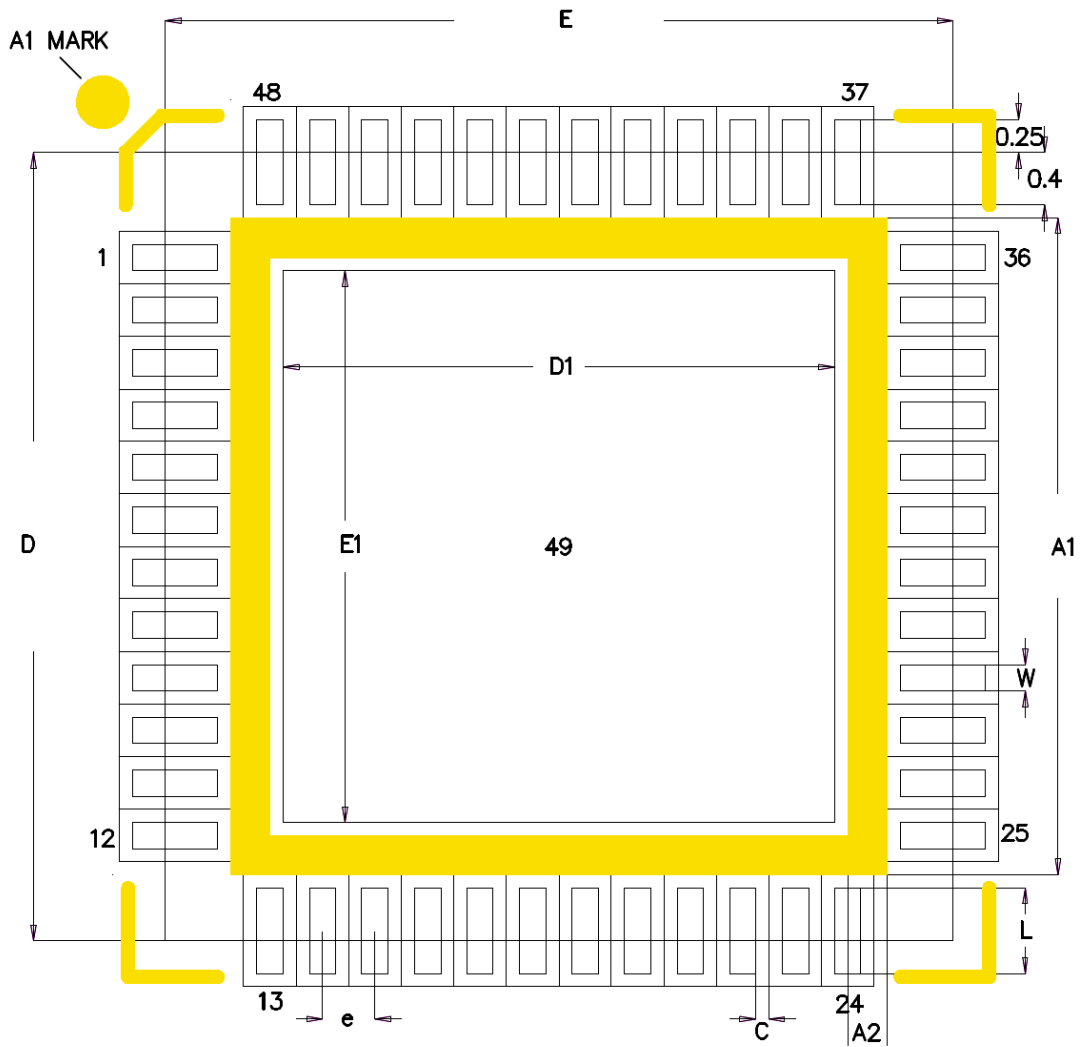
13.3 PACKAGE DETAIL

QFN48 6x6 Chip Outline (IS2008S /IS2010S)

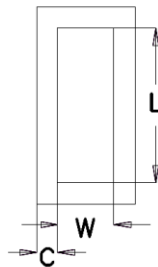


		SYMBOL	MIN	NOM	MAX
TOTAL THICKNESS		A	0.8	0.85	0.9
STAND OFF		A1	0	0.035	0.05
MOLD THICKNESS		A2	---	0.65	0.67
L/F THICKNESS		A3	0.203 REF		
LEAD WIDTH		b	0.15	0.2	0.25
BODY SIZE	X	D	6 BSC		
	Y	E	6 BSC		
LEAD PITCH		e	0.4 BSC		
EP SIZE	X	J	4.1	4.2	4.3
	Y	K	4.1	4.2	4.3
LEAD LENGTH		L	0.35	0.4	0.45
PACKAGE EDGE TOLERANCE		aaa	0.1		
MOLD FLATNESS		bbb	0.1		
COPLANARITY		ccc	0.08		
LEAD OFFSET		ddd	0.1		
EXPOSED PAD OFFSET		eee	0.1		

QFN48 6x6 PCB Footprint (IS2008S /IS2010S)



TOP VIEW



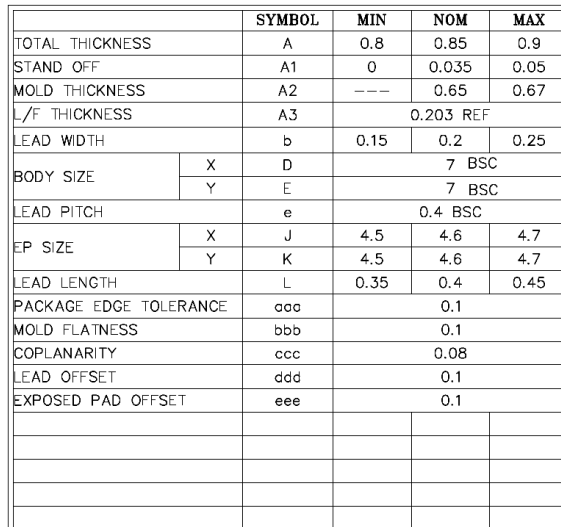
SOLDERMASK OPENING OUTSIDE OF LAND

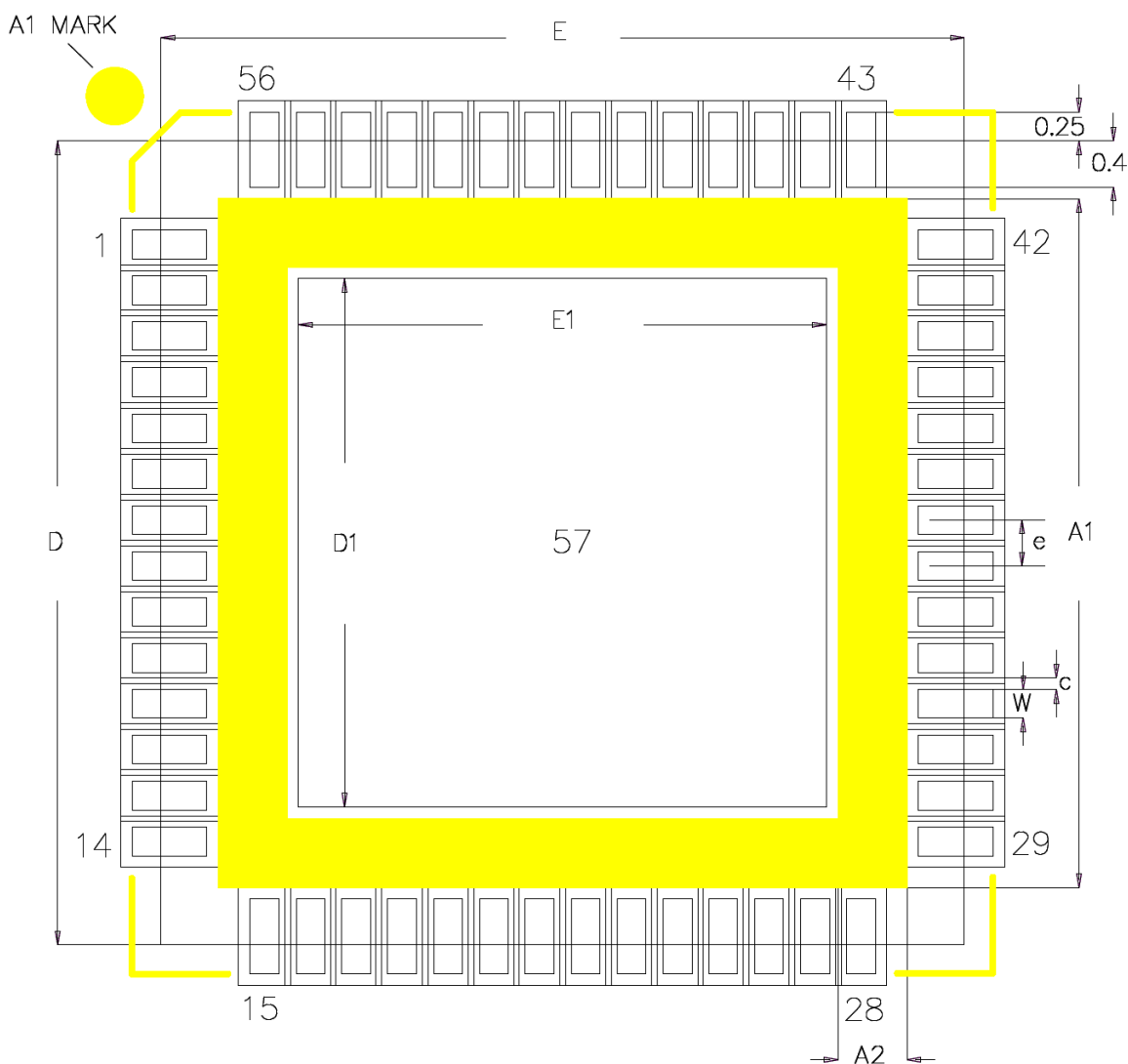
	SYMBOL	COMMON DIMENSIONS		
		MIN.	NOR.	MAX.
SILKSCREEN TOP L	A1		5	REF
SILKSCREEN TOP W	A2		0.3	REF
BODY SIZE	D		6	BSC
	E		6	BSC
EXPOSED PAD SIZE	D1		4.2	BSC
	E1		4.2	BSC
PEAD LENGTH	L		0.65	
PEAD WIDTH	W		0.2	
SOLDER MASKER OPEN	c		0.1	
PEAD PITCH	e		0.4	
PEAD COUNT	n1		48	

UNIT : MM

QFN56 7x7 Chip Outline (IS2013S / IS2015S)

QFN56 7x7 PCB Footprint (IS2013S / IS2015S)





TOP VIEW



SOLDERMASK OPENING OUTSIDE OF LAND

	SYMBOL	COMMON DIMENSIONS		
		MIN.	NOR.	MAX.
SILKSCREEN TOP L	A1		6	REF
SILKSCREEN TOP W	A2		0.6	REF
BODY SIZE	D		7	BSC
	E		7	BSC
EXPOSED PAD SIZE	D1		4.6	BSC
	E1		4.6	BSC
LEAD LENGTH	L		0.65	
LEAD WIDTH	W		0.25	
SOLDER MASKER OPEN	c		0.1	
LEAD PITCH	e		0.4	
LEAD COUNT	n1		56	

14.0 REFLOW PROFILE AND
STORAGE CINDITION

UNIT : MM

14.1 STENCIL OF SMT ASSEMBLY SUGGESTION

14.1.1 STENCIL TYPE & THICKNESS

Laser cutting
Stainless steel
Thickened
0.5 mm Pitch: thickness < 0.15 mm

14.1.2 APERTURE SIZE AND SHAPE FOR TERMINAL PAD

Aspect ratio (width/thickness) > 1.5

Aperture shape

- The stencil aperture is typically designed to match the pad size on the PCB.
- Oval-shaped opening should be used to get the optimum paste release.
- Rounded corners to minimize clogging.
- Positive taper walls (5° tapering) with bottom opening larger than the top.

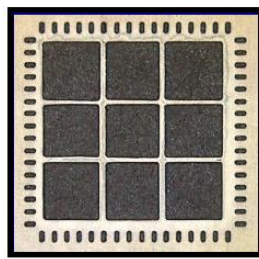
14.1.3 APERTURE DESIGN FOR THERMAL PAD

The small multiple openings should be used in steady of one big opening.

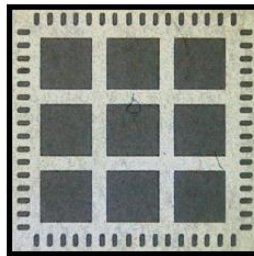
60~80% solder paste coverage

Rounded corners to minimize clogging

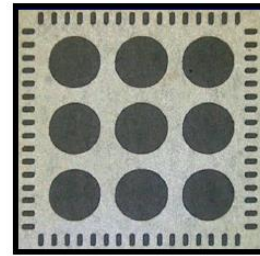
Positive taper walls (5° tapering) with bottom opening larger than the top



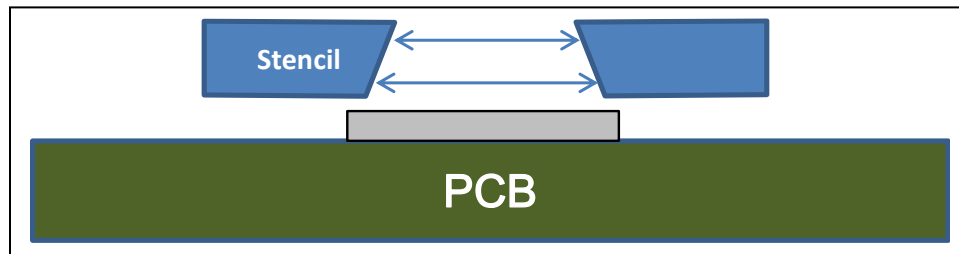
Don't recommend
Coverage 91%



Recommend
Coverage 77%



Recommend
Coverage 65%



14.2 REFLOW CONDITION

1.) Follow : IPC/JEDEC J-STD-020

2.) Condition :

Average ramp-up rate (217°C to peak): 1~2°C/sec max.

Preheat : 150~200°C 、 60~180 seconds

Temperature maintained above 217°C : 60~150 seconds

Time within 5°C of actual peak temperature: 20 ~ 40 sec.

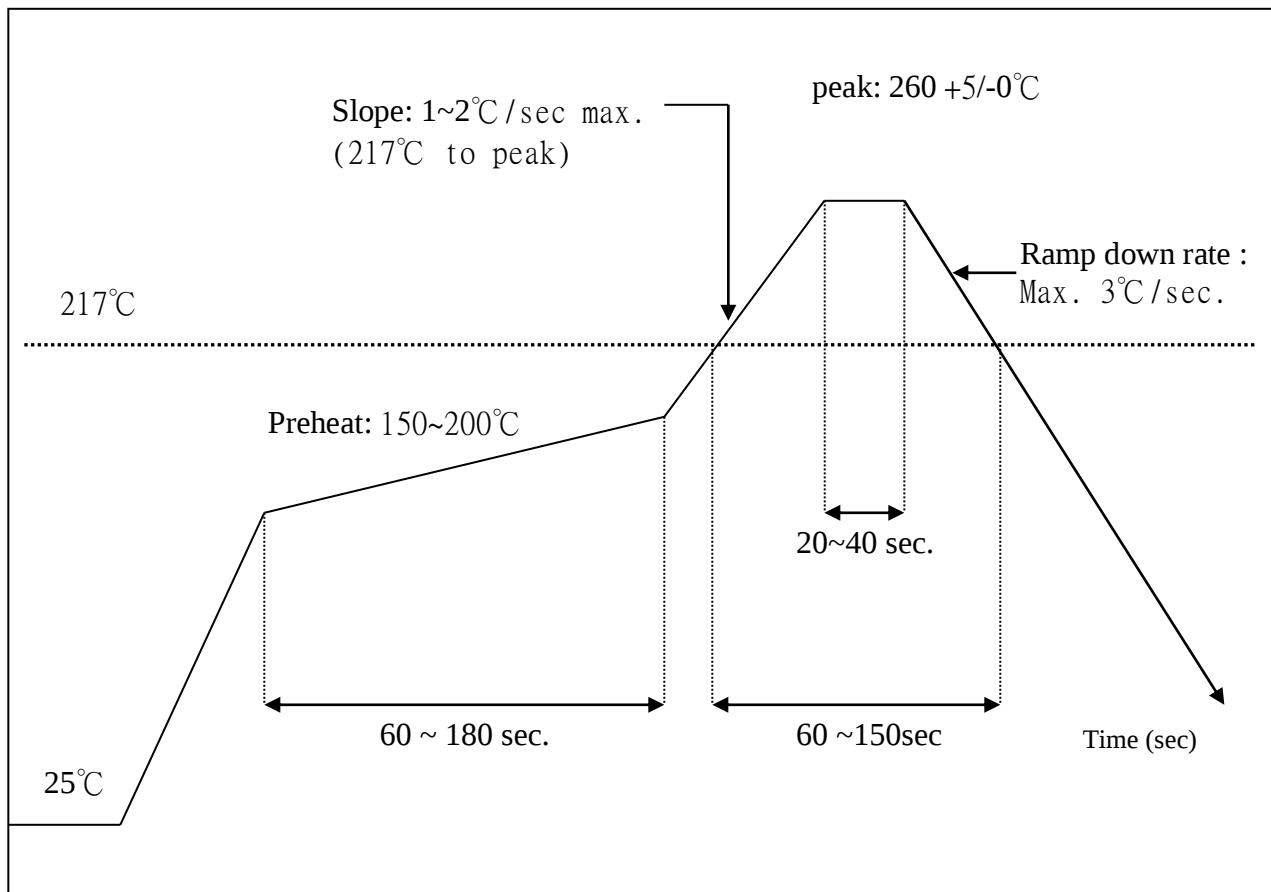
Peak temperature : 260 +5/-0 °C

Ramp-down rate : 3°C/sec. max.

Time 25°C to peak temperature : 8 minutes max.

Cycle interval : 5 minus

FIGURE 14-1: REFLOW PROFILE



14.3 STORAGE CONDITION

1. Calculated shelf life in sealed bag: 24 months at $< 40^{\circ}\text{C}$ and $<90\%$ relative humidity (RH)
2. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must be Mounted within 168 hours of factory conditions $<30^{\circ}\text{C}/60\%$ RH

FIGURE 14-2: LABEL OF CHIP BAG

(Please notice the baking requirement)

	Caution This bag contains MOISTURE-SENSITIVE DEVICES	LEVEL 3 If blank, see adjacent bar code label
1. Calculated shelf life in sealed bag : 24 months at $< 40^{\circ}\text{C}$ and $<90\%$ relative humidity (RH) 2. Peak package body temperature: _____$^{\circ}\text{C}$ If blank, see adjacent bar code label 3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must be a) Mounted within: 168 hours of factory conditions If blank, see adjacent bar code label $\leq 30^{\circ}\text{C}/60\%$ RH, or b) Stored per J-STD-033 4. Devices require bake, before mounting, if: a) Humidity Indicator Card reads $> 10\%$ for level 2a - 5a devices or $> 60\%$ for level 2 devices when read at $23 \pm 5^{\circ}\text{C}$ b) 3a or 3b are not met. 5. If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure.		
Bag Seal Date: _____ If blank, see adjacent bar code label		
Note: Level and body temperature defined by IPC/JEDEC J-STD-020		